

# Rectifier diode

SMAF 200 V



For surface mount applications  
Low profile package  
Glass passivated chip junction

**SPECIFICATION:**

Peak off-state voltage	200 V
Forward current	1.0 A
Recovery time	35 ns
Housing type	SMAF
Configuration	Single
Operating temperature	-55...+150 °C
Conducting-state voltage	1.0 V
Off-state current	5 µA



Art. Nr.  
RND ES1DF-AT

